

## IN THE U.S. PATENT AND TRADEMARK OFFICE

In re application of

Noboru SAKIMURA et al.

Conf. 1343

Application No. 10/553,998 Group 2827

Filed October 21, 2005

Examiner Tan Nguyen

MAGNETIC RANDOM ACCESS MEMORY WITH DATA READING METHOD IMPROVED

## **AMENDMENT**

Assistant Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

June 6, 2008

Sir:

In response to the Official Action of February 14, 2008, please amend the above-identified application as follows:

Amendments to the Specification begin on page 2 of this paper.

Amendments to the Claims are reflected in the listing of claims which begins on page 3 of this paper.

Remarks begin on page 30 of this paper.